TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET

TLP3111

Measurement Instruments

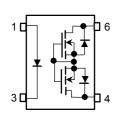
Logic IC Testers / Memory Testers Board Testers / Scanners

The TOSHIBA mini flat photo relay TLP3111 is a small outline photo relay, suitable for surface mount assembly.

The TLP3111 consists of a GaAs infrared emitting diode optically coupled to a photo–MOSFET in a 4 pin lead package (MFSOP6), and has characteristics of small off–state current and small output terminal capacitance, which enable the TLP3111 to be applied to measurement instruments.(especially to high–frequency measurements)

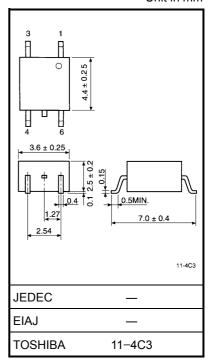
- 1-form-A
- Peak off-state voltage: 80V(min.)
- Trigger LED current: 4mA(max.)
- On-state current: 100mA(max.)
- On-state resistance: 20Ω(max.)
- Isolation voltage: 1500V_{rms}(min.)

Pin Configurations (top view)



- 1 : Anode
- 3: Cathode
- 4 : Drain
- 6 : Drain

Unit in mm



Weight: 0.1 g

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current		50	mA
LED	Reverse voltage	V _R	6	V
	Junction temperature	Tj	125	°C
or	Off-state output voltage	V _{OFF}	80	V
Detector	On-state current	I _{ON}	100	mA
ă	Junction temperature	Tj	125	°C
Sto	rage temperature	T _{stg}	-40~125	°C
Оре	erating temperature	T _{opr}	-20~85	°C
Lea	d solder temperature (10 s)	T _{sol}	260	°C
Isol	ation voltage (AC, 1 min., R.H.≤ 60%) (Note 1)	BVS	1500	V _{rms}

(Note 1): Device considered a two-terminal device: Pins 1 and 3 shorted together, and pins 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{OFF}	_	_	64	V
Forward current	I _F	10	_	30	mA
On-state current	I _{ON}	_	_	100	mA
Operating temperature	T _{opr}	25	_	50	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = 20 mA	1.0	1.2	1.4	V
LED	Reverse voltage	I _R	V _R = 6 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	15	_	pF
Detector	Off-state current	l _{OFF}	V _{OFF} = 30 V, Ta = 50°C		0.05	1	nA
Dete	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	11	15	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIn.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	I _{ON} = 100 mA	_	_	4	mA
On-state resistance	R _{ON}	I _{ON} = 100 mA, I _F = 5 mA	_	16	20	Ω

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Isolation Characteristics (Ta = 25°C)

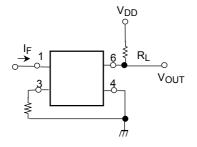
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V _S = 0 V, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	1500	_	_	V
Isolation voltage	BV_S	AC, 1 second (in oil)	_	3000	_	V _{rms}
		DC, 1 minute (in oil)	_	3000	_	V_{dc}

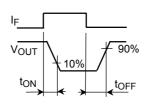
Switching Characteristics (Ta = 25°C)

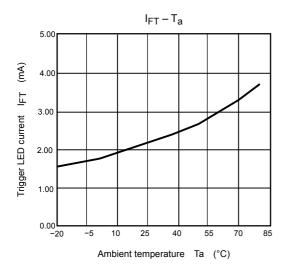
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time		$R_L = 200 \Omega$ (Note2)	_	_	1	ms
Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 10 \text{ mA}$	_	_	1	1113

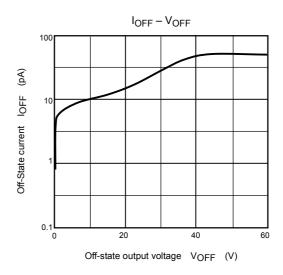
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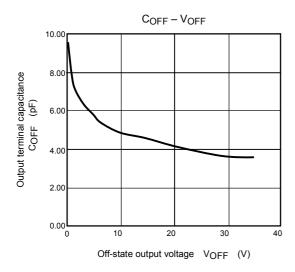
(Note2): Switching time test circuit











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